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# Introduction

Solid-state batteries (SSBs) represent emerging kinds of energy storage systems which possess the virtues of high safety, high energy density and long cycle life.<sup>1–3</sup> One of the key challenges for SSBs is to develop secure and reliable solid electrolytes exhibiting good compatibility with electrode materials.<sup>2,4,5</sup> On the one hand, researchers are seeking new solid-state ionic conductors such as chalcogenides,<sup>6,7</sup> halides<sup>8</sup> and complex hydrides<sup>9,10</sup> to break the limit. However, these new solid electrolytes suffer from severe interfacial stability against either highly reductive metal anodes or cathode materials with high oxidation potential, limiting their further application in high-voltage SSBs.<sup>4,11–14</sup> On the other hand, new concepts and methods are proposed to improve classic oxide-based solid ionic conductors such as  $\beta$ -Al<sub>2</sub>O<sub>3</sub> and NASICONs for vast application under ambient conditions.<sup>15–21</sup>

Recently, increasing research attention has been paid to the interface between the NASICON-type solid electrolyte and Na metal. Wang *et al.*<sup>22</sup> investigated Na metal/NASICON interface chemistry and its consequent interphase and pointed out that the interphase with high electron conductivity is the main cause

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# Optimizing the Na metal/solid electrolyte interface through a grain boundary design<sup>†</sup>

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Poor compatibility between an alkaline metal electrode and solid electrolyte at interfaces is the critical issue for solid-state metal batteries. We propose a grain boundary sealing (GBS) design of the Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> (denoted as GBS-NZSP) solid electrolyte to enhance interfacial contact with Na metal and realize stable Na plating/stripping cycles at room temperature.  $(ZnO)_2-(B_2O_3)_3$  (ZBO) is selected to promote densification sintering of NZSP and seal the grain boundary from electrons, thus suppressing Na metal dendrite growth and maintaining interfacial stability during charge/discharge cycles. The optimal GBS-NZSP reaches an impressive interfacial resistance of 23  $\Omega$  cm<sup>2</sup>, over 41 times lower than that of bare NZSP against Na metal at 25 °C. The corresponding symmetrical Na//Na cell preserves super cycling stability for 1400 h at 0.3 mA cm<sup>-2</sup>. The excellence is attributed to the positive effect of the GBS design on enhanced ionic conductivity and reduced electron transfer at the grain boundary, which leads to steady high-flux Na<sup>+</sup>-ion migration across the solid electrolyte without dendrite formation. Moreover, a 4 V full cell of Na<sub>3</sub>V<sub>1.5</sub>Cr<sub>0.5</sub>(PO<sub>4</sub>)<sub>3</sub>/GBS-NZSP/Na is assembled accordingly, exhibiting high-rate capability and delivering a capacity of 108 mA h g<sup>-1</sup> for 560 cycles with over 80% retention at 10C rate.

> for interfacial instability. Gao et al.23 considered that a very thin NaO<sub>x</sub> layer is formed at the Na metal/NASICON interface, which hinders electron transfer and works as a stable interphase. Differently, Huang and co-workers<sup>24</sup> revealed that a Na<sub>2</sub>CO<sub>3</sub>dominant barrier layer on the surface of Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> is responsible for the unfavourable interface against Na metal and they improved the interfacial performance through a postthermal treatment of Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub>. Besides, chemical coating or surface modification by using TiO<sub>2</sub>,<sup>25</sup> AlF<sub>3</sub>,<sup>26</sup> and hot Na metal<sup>27</sup> has been conducted to enhance the contact at the Na metal/NASICON interface but achieves limited effect at room temperature. Lu et al.<sup>18</sup> proposed a tri-layer design for Na<sub>3</sub>Zr<sub>2</sub>-Si<sub>2</sub>PO<sub>12</sub> with a SnO<sub>2</sub> modified porous surface, which realizes much reduced interfacial resistance from 10 k $\Omega$  cm<sup>2</sup> to 275  $\Omega$ cm<sup>2</sup>, promoting stable Na plating/stripping cycles for 600 h at 0.3 mA cm<sup>-2</sup> at room temperature. Mao et al.<sup>28</sup> introduced a simple room-temperature ultrasonic welding method to enhance the contact between Na metal and Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub>. The interfacial resistance substantially decreases after the ultrasonic welding treatment and Na plating/striping cycles are readily achieved at 0.2 mA cm<sup>-2</sup> for 400 h. However, these studies have paid intensive attention to post treatment on Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> without focusing on regulation of its intrinsic features, such as the grain microstructure, grain boundary, chemical doping, etc. Moreover, methods towards better interfacial performance of low interfacial resistance and steady charge/discharge cycles at high current densities are still highly desired.

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In this work, we present a grain boundary sealing design of Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> (denoted as GBS-NZSP) to optimize the interface against Na metal at high current densities at room temperature. A liquid-phase sintering method using the inorganic  $(ZnO)_2$ - $(B_2O_3)_3$  (ZBO) additive is adopted to synthesize GBS-NZSP, which contains highly crystalline NZSP grains and grain boundary strengthen by ZBO. The optimized GBS-NZSP realizes a much lower interfacial resistance of 27  $\Omega$  cm<sup>2</sup> against Na metal and a higher critical current density of  $0.55 \text{ mA cm}^{-2}$  than those of bare NZSP. The corresponding symmetrical Na/GBS-NZSP/Na exhibits steady Na plating/stripping cycles and small polarization for as long as 1400 h at a high current density of 0.3 mA cm<sup>-2</sup>. Accordingly, a 4 V full cell of Na<sub>3</sub>V<sub>1.5</sub>Cr<sub>0.5</sub>(PO<sub>4</sub>)<sub>3</sub>/GBS-NZSP/Na is enabled at room temperature, showing low resistance and excellent high-rate cyclability. Our results provide valuable guidance for design and synthesis of highperformance solid electrolytes applicable in high-rate rechargeable solid-state batteries under ambient conditions.

# **Results and discussion**

As shown in Fig. 1a, the GBS-NZSP solid electrolyte is synthesized through a liquid-phase sintering method using the ZBO additive whose melting point is 800.9 °C (Fig. S1<sup>+</sup>). Based on sintering theory, the ZBO additive melting provides a liquidphase environment for pre-sintered Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> grains, thus accelerates mass diffusion and promotes grain boundary reactivity.<sup>29,30</sup> After cooling down and grain shrinkage, ZBO remains to fill the grain boundary. In this way, densification sintering of GBS-NZSP at a much lower temperature of 1000 °C than that of pristine NZSP (above 1250 °C) is realized. XRD patterns of GBS-NZSP samples with various ZBO molar ratios (x)of 0-0.3 are mainly indexed to the monoclinic Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> phase structure of the c2/c space group (Fig. S2<sup>†</sup>). Diffraction peaks at  $2\theta = 24.04^{\circ}$ ,  $24.44^{\circ}$ ,  $28.12^{\circ}$ ,  $31.44^{\circ}$  correspond to (011), (110), (-111), and (111) planes of a monoclinic  $ZrO_2$  phase, which results from unreacted ZrO2 and minor sodium volatilization in high-temperature solid reactions.<sup>31</sup> Additionally, for x = 0.3, there appears a new diffraction peak at  $2\theta = 26.99^{\circ}$ 

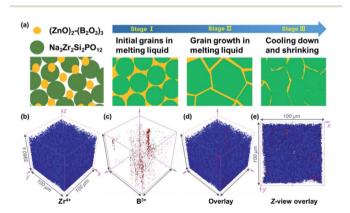
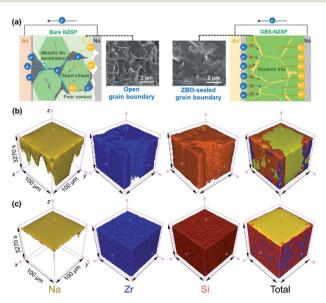


Fig. 1 (a) Schematic of the liquid-phase sintering of GBS-NZSP using the ZBO additive and (b–e) the 3D rendered model of the selected sample with ZBO molar ratio x = 0.2 according to the depth profile by ToF-SIMS.

belonging to the (200) plane of a tetragonal ZrSiO<sub>4</sub> phase formed by the excess ZBO addition.30 Since there are no XRD diffraction peaks relevant to the ZBO additive, we consider that it is in a glassy state adhesive on the Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub> grains. This result is similar to the situation where a sodium borate-based additive is used.<sup>30-32</sup> Given that B as a light element is difficult to be detected by energy dispersive X-ray spectrometry (EDS), we characterize the position of B by in-depth time of flight secondary ion mass spectrometry (ToF-SIMS). 3D rendered models according to the depth profile of GBS-NZSP (x = 0.2) by ToF-SIMS shown in Fig. 1b-e reveal that B<sup>3+</sup> ions amorphously gather along the gaps of the Zr<sup>4+</sup> bulk, indicating the existence of borate compounds at the grain boundary. Such a result agrees with the liquid-phase sintering theory, where the unreacted sintering additive is dissolved or dispersed at the grain boundary.<sup>29,30</sup> Apparent densities of the samples are measured by the Archimedes drainage method to obtain the relative density against the theoretical density of monoclinic  $Na_3Zr_2Si_2PO_{12}$  (3.244 g cm<sup>-3</sup> at 25 °C).<sup>33</sup> The relative density increases as the ZBO ratio increases from 0 to 0.2, and the highest relative density of 99.8% is reached, substantially higher than that of bare NZSP (73.7%) (Fig. S3<sup>†</sup>).

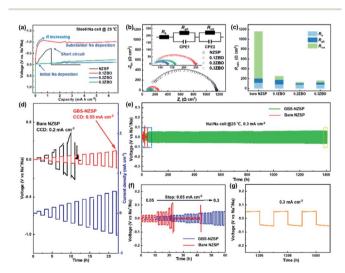
We select SEM images of the GBS-NZSP sample with x = 0.2and bare NZSP for comparison, among which NZSP contains loosely connected polyhedrons and gaps, while GBS-NZSP shows a denser microstructure (inset in Fig. 2a). When used in batteries for Na metal plating, the unsound NZSP undergoes uneven Na metal plating because of poor interfacial contact and Na accumulation at the grain boundary, which eventually leads to electron conductivity, Na dendrite formation and short circuits. In contrast, the densely sintered NZSP-ZBO allows



**Fig. 2** Comparison between bare NZSP and GBS-NZSP for Na plating. (a) Schematic of Na metal dendrite penetration across NZSP with an open grain boundary (inset left SEM image) and dendrite-free Na plating using GBS-NZSP with the ZBO-sealed grain boundary (inset right SEM image). 3D rendering models based on the depth scan of (b) NZSP and (c) GBS-NZSP after Na plating by ToF-SIMS.

high-flux and dendrite-free Na<sup>+</sup>-ion migration because of the GBS effect in reducing electron transfer and enhancing ionic conductivity at the grain boundary. As a result, stable Na plating and tight interfacial contact are achieved (Fig. 2a). Fig. 2(b) and (c) compare the 3D rendering models of positive ions based on the depth scan of NZSP and GBS-NZSP by ToF-SIMS after Na plating for over 6 h. The bare NZSP encounters unfavorable Na metal penetration into the solid electrolyte bulk, while GBS-NZSP possessing dense structure renders uniform Na metal plating on the surface without dendtrite formation.

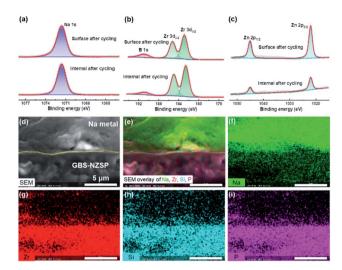
Galvanostatic Na plating curves of steel//Na cells using GBS-NZSP with an x variation of 0.1–0.3 and bare NZSP as solid electrolytes are collected at a current density of 0.1 mA cm<sup>-2</sup>. As shown in Fig. 3a, a rapid short circuit of NZSP occurs when the cell reaches a voltage of -0.71 V and a capacity of 1.28 mA h cm<sup>-2</sup>. For x = 0.1, the cell shows a sharp voltage ramp to -1.08 V at the initial stage and then the voltage gradually decreases to a plateau of around -0.98 V. Minor addition of ZBO shows a robust grain boundary effect and significantly improves the Na plating behaviour without fast short circuits. Further, for x = 0.2 and 0.3, the voltages of Na plating are much smaller, below 0.1 V even after a Na plating capacity of over 2.0 mA h  $cm^{-2}$  is achieved, indicating essentially reduced interfacial resistance and stability of GBS-NZSP against Na metal. Impressively, the optimal GBS-NZSP performs continuous Na plating with a capacity of up to 6.6 mA h  $cm^{-2}$  at a voltage as low as 0.11 V, exhibiting super ability of convenient Na plating at room temperature. Room-temperature electrochemical impedance spectroscopy (EIS) analysis of symmetrical



**Fig. 3** Cell performance using bare NZSP and GBS-NZSP (x = 0.1-0.3) as solid electrolytes measured at 25 °C. (a) Na plating plots of steel//Na cells, (b) Nyquist plots of symmetrical Na//Na cells with an inset equivalent circuit and (c) corresponding comparison of the calculated  $R_{\rm b}$ ,  $R_{\rm gb}$ , and  $R_{\rm int}$  values between bare NZSP and GBS-NZSP (x = 0.1-0.3). (d) Critical current densities of GBS-NZSP (x = 0.2) and bare NZSP for comparison. (e) Na plating/stripping cycling profile of the Na/GBS-NZSP/Na cell at stepwise current densities from 0.05 to 0.3 mA cm<sup>-2</sup> for 1400 h and the corresponding selected cycling profile during (f) 0–60 h, (g) 1395–1401 h. In (e) and (f), the cycling profile of the Na/bare NZSP/Na cell is provided for comparison.

Na//Na cells is conducted to clarify the interfacial resistance in the Na metal/solid electrolyte. Fig. 3b shows the Nyquist plots of the Na//Na cells using bare NZSP and GBS-NZSP (x = 0.1-0.3) as solid electrolytes measured at 25 °C. The inset is a suggested equivalent circuit according to previous literature,<sup>34</sup> which contains three resistance components in series: bulk resistance  $(R_{\rm b})$ , resistance at the grain boundary  $(R_{\rm gb})$  of the solid electrolyte and interfacial resistance  $(R_{int})$  at the interface against Na metal. Fig. 3c shows the comparison of the as-calculated  $R_{\rm b}$ ,  $R_{\rm gb}$ , and  $R_{\rm int}$  between bare NZSP and GBS-NZSP (x = 0.1-0.3). For bare NZSP,  $R_{\rm b}$ ,  $R_{\rm gb}$ , and  $R_{\rm int}$  are calculated to be 117.7  $\Omega$  cm<sup>2</sup>, 85.0  $\Omega$  cm<sup>2</sup>, and 957.4  $\Omega$  cm<sup>2</sup>, respectively, giving a total resistance of 1160.1  $\Omega$  cm<sup>2</sup>. The symmetrical cells using GBS-NZSP (x = 0.1-0.3) solid electrolytes exhibit much lower resistance, demonstrating the significant effect of the GBS design by adding the ZBO additive into NZSP to simultaneously enhance both the grain boundary and the interfacial Na<sup>+</sup>-ion transport. Among them, GBS-NZSP (x = 0.2) exhibits the optimal electrochemical impedance nature and especially shows a desired low  $R_{\rm int}$  of 23.3  $\Omega$  cm<sup>2</sup>, which is over 41 times smaller than that of bare NZSP and over 25 times smaller than that of a densely sintered NZSP-1250 (Fig. S4a†). Typically, we perform the critical current density (CCD) measurement under galvanostatic Na plating/stripping cycles. As shown in Fig. 3d, the CCD of GBS-NZSP (x = 0.2) is more than 2 times higher than that of NZSP, indicating improved stability for Na plating/stripping cycles. Further, long-term galvanostatic Na plating/stripping cycles are conducted in a symmetrical Na/GBS-NZSP/Na cell. The overall cycling profile during cycling for 1400 h is shown in Fig. 3e which exhibits stable and small polarization voltages under the stepwise current densities from 0.05 to 0.3 mA cm<sup>-2</sup>. Detailed cycling curves for the initial 0-60 h and the final 1395-1401 h are presented in Fig. 3f and g, respectively. There are no obvious voltage fluctuations at a continuously increasing current density from 0.05 to 0.3 mA  $\text{cm}^{-2}$  with 5 cycles for each step. The polarization voltage for reversible Na plating/stripping at  $0.3 \text{ mA cm}^{-2}$  is only 53 mV, which is well retained for as long as 1400 h. In comparison, the symmetrical cell using bare NZSP shows a large polarization voltage and rapid short circuit after cycling for 23 h at 0.15 mA cm $^{-2}$ . Moreover, the cycling profile of the symmetrical Na//Na cells using NZSP-1250, and GBS-NZSP at x = 0.1 and 0.3 as solid electrolytes is provided in Fig. S4,† none of which can maintain long-time stable Na plating/ stripping cycling at a current density of over 0.2 mA  $\text{cm}^{-2}$ . GBS-NZSP, which is synthesized by an energy-saving lowtemperature sintering method and used without any post surface or chemical modification, exhibits excellent performance competitive with other solid electrolytes.15,18,24,25,28,35-38 A detailed comparison including the cell resistance, interfacial resistance, current density and stability is provided in Table S1<sup>+</sup> to further signify the advantage and novelty of the well-designed GBS-NZSP solid electrolyte for sodium metal batteries.

We disassemble the symmetrical cell to analyse the chemical states and morphology of GBS-NZSP (x = 0.2) after Na plating/ stripping cycles for 1400 h. Typical Na 1s, B 1s, Zr 3d and Zn 2p spectra after cycling are exhibited in Fig. 4 with comparison between the upper surface and the internal section. The Na 1s



**Fig. 4** Interface analysis of GBS-NZSP (x = 0.2) after Na plating/ stripping cycles. XPS spectra of (a) Na 1s, (b) Zr 3d and B 1s, (c) Zn 2p with the comparison between the upper surface and the internal cross section. (d) SEM image and (e–i) corresponding elemental mapping images of the cross-sectional Na-metal capped GBS-NZSP.

spectra show no difference in the peak binding energy (1071.6 eV) between the surface and internal section (Fig. 4a). B 1s peaks at 190.9 eV are observed for both the surface and internal section, indicating the existence of B<sup>3+</sup> in GBS-NZSP. The Zr 3d spectra split into two peaks at 185.3 and 182.9 eV, ascribed to Zr 3d<sub>3/2</sub> and 3d<sub>1/2</sub>, respectively (Fig. 4b). Previous literature has reported reduced  $Zr^{(4-x)+}$  species on the surface of bare NZSP after Na plating/stripping cycles.15,22,39 Differently, here the cycled GBS-NZSP maintains Zr4+ without reduction on the surface, implying excellent chemical stability against the highly reductive Na metal. Reduced  $Zn^{(2-x)+}$  species are neither observed on the surface nor on the internal section (Fig. 4c), denying the formation of low-valence Zn compounds for unfavourable electron conductivity. The Si 2p, P 2p and O 1s spectra are presented in Fig. S4<sup>†</sup> to further support the point above. Therefore, it is indicated a stable interphase is formed between Na metal and GBS-NZSP, which suppresses reductive Na metal penetration into the solid electrolyte and facilitates uniform Na metal plating/stripping cycles. Cross-sectional morphology observation of Na metal caped GBS-NZSP is conducted by using a SEM equipped with an energy dispersive spectrometer (EDS). As shown in Fig. 4d, metallic Na maintains closely conformal contact with GBS-NZSP even after long-term cycling for 1400 h. Besides, the elemental mapping images shown in Fig. 4e-i indicate the intimate adhesion of metallic Na on the surface of GBS-NZSP and no Na dendrites are observed. It proves that not only the chemical composition of GBS-NZSP but also the desired interfacial contact is retained during Na plating/stripping cycles, explaining the super cycling stability and low interfacial resistance.

According to the discussion above, we describe the Na plating behaviour of the solid electrolytes shown in Fig. 5 with comparison between the unsound NZSP and the optimal GBS-NZSP. The former contains unclosed grain boundaries and

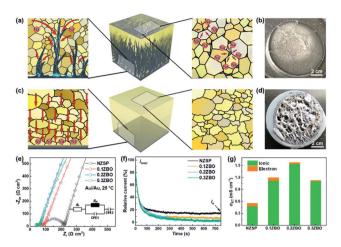
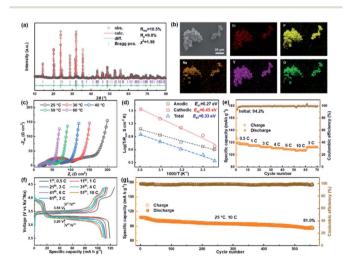


Fig. 5 (a) Schematic of bare NZSP breeding Na metal dendrite growth and (b) its optical picture after Na plating. (c) Schematic of GBS-NZSP permitting high-flux Na<sup>+</sup>-ion migration without dendrite formation and (d) its optical picture after Na plating. (e) Nyquist plots calibrated by the surface areas of the solid electrolyte discs and (f) normalized polarization curves of NZSP and GBS-NZSP with a ZBO content variation of 0.1–0.3 collected at room temperature. (g) Room-temperature conductivities of the samples with calculated ionic and electron contributions.

pores, which become the bottlenecks of Na<sup>+</sup>-ion migration at high current densities. The blocked Na<sup>+</sup> ions in these places then combine with electrons and Na plating subsequently occurs, breeding a curse for Na metal penetration across the solid electrolyte (Fig. 5a). Consequently, short circuits and mechanical breakdown of the solid electrolyte eventually take place (Fig. 5b). In sharp contrast, the well-designed GBS-NZSP allows high-flux Na<sup>+</sup>-ion migration and enables high-rate Na plating/stripping cycles without dendrite penetration (Fig. 5c and d). We measure the Nyquist plots of the solid electrolytes with ZBO content variation x = 0-0.3 by using sputtering Au films as blocking electrodes to obtain the total conductivity  $(\sigma_t)$ at room temperature. Fig. 5e shows the Nyquist plots calibrated by the surface areas of the solid electrolyte discs and the thicknesses (L) for x = 0, 0.1, 0.2, 0.3 are measured to be 0.107 mm, 0.101 mm, 0.090 mm, and 0.086 mm, respectively by using a micrometre. The total conductivities for x = 0, 0.1, 0.2, 0.3 are calculated to be 0.53 mS  $cm^{-1}$ , 1.19 mS  $cm^{-1}$ , 1.58 mS  $cm^{-1}$ , and 1.13 mS cm<sup>-1</sup>, respectively through *L/R*. To clarify the contribution from electrons, polarization curves are further measured using a Au film as the blocking electrode and the result is shown in Fig. 5f. It is found that the current contribution by electron transfer decreases as the ZBO content increases. GBS-NZSP samples exhibit much lower electron currents than that of bare NZSP. As shown in Fig. 5g, GBS-NZSP (x = 0.2) exhibits the highest conductivity of 1.58 mS cm<sup>-1</sup> with the smallest electron contribution of 1.8% at room temperature, while the electron contributions from bare NZSP, x = 0.1 and x= 0.3 are 15.3%, 7.1%, and 2.2%, respectively. This result supports the effect of GBS on hindering electron transfer and dendrite formation across the solid electrolyte.

NASICON-type cathode materials for sodium ion batteries are advantageous because of their high Na<sup>+</sup>-ion conductivity, convenient structural design and excellent cycling stability.40-43 We assemble a solid-state sodium metal battery of Na<sub>3</sub>V<sub>1.5</sub>-Cr<sub>0.5</sub>(PO<sub>4</sub>)<sub>3</sub>/GBS-NZSP/Na using a NASICON-type Na<sub>3</sub>V<sub>1.5</sub>Cr<sub>0.5</sub>(-PO<sub>4</sub>)<sub>3</sub> (NVCP) cathode synthesized through a sol-gel method.<sup>41</sup> The retrieved refined XRD pattern of the as-synthesized NVCP is shown in Fig. 6a, confirming that NVCP belongs to a space group of R3c derived from a NASICON-type phase of  $Na_3V_2(PO_4)_3$ . Detailed cell parameters and atomic position data are provided in Table S2.† The SEM image along with the EDS mapping image shown in Fig. 6b indicates the existence of Na, V, Cr, P, and O uniformly distributed in NVCP microparticles. Besides a polyvinylidene fluoride (PVDF) binder and carbon black conductive additive, a NaClO4-succinonitrile plastic crystal electrolyte (PCE) is further added as an ionic conductor additive for the composite NVCP cathode.<sup>44</sup> Fig. 6c shows the temperature-dependent Nyquist plots of the solidstate battery in the range of 25-60 °C, showing similarities of an increment on the  $Z_r$  axis, two connected semicircles and a linear tail from a high frequency to a low frequency. The increment corresponds to the resistance of the GBS-NZSP solid electrolyte  $(R_{SE})$ . The first semicircle is relevant with the anodic interface charge transfer ( $R_{ct,anodic}$ ), while the second semicircle is attributed to the cathodic one  $(R_{ct,cathodic})$ . It is derived that  $R_{\rm ct,anodic}$ ,  $R_{\rm ct, cathodic}$  and  $R_{\rm total}$  at 25 °C are 75.9  $\Omega$  cm<sup>2</sup>, 71  $\Omega$  cm<sup>2</sup> and 173.6  $\Omega$  cm<sup>2</sup>, respectively. The corresponding conductivity activation energies ( $E_{a1}$ ,  $E_{a2}$ , and  $E_{a3}$ ) are calculated to be 0.27 eV, 0.45 eV, and 0.33 eV, respectively (Fig. 6d). The small resistance and low activation energy signify the good temperature adaptability of the solid battery. Fig. 6e depicts the rate performance of the solid battery at stepwise rates in the range of 0.5-10C (1C = 121 mA g<sup>-1</sup>) at 25 °C. The first charge and



**Fig. 6** Characterization of the NVCP cathode material and the electrochemical performance of the solid-state NVCP/GBS-NZSP/Na battery. (a) Rietveld refined XRD pattern (b) SEM image of NVCP with the EDS mapping image. (c) Temperature-dependent Nyquist plots and (d) Arrhenius plots in the range of 25-60 °C. (e) Rate performance at 0.5–10C and (f) corresponding charge/discharge profile in the voltage range of 2.5-4.4 V vs. Na<sup>+</sup>/Na. (g) Cycling performance at 10C.

discharge capacities are 126.5 and 119.1 mA h  $g^{-1}$ , respectively, giving an initial coulombic efficiency of 94.2% higher than that of a liquid battery using the same cathode material.<sup>41,42</sup> More importantly, the solid-state battery exhibits a satisfactory highrate performance at 10C, showing a capacity of 108.1 mA h  $g^{-1}$ as high as over 89% that of the theoretical capacity.41,42 The charge/discharge profile at various rates is shown in Fig. 6f, consisting of two discharge plateaus of  $V^{5+}/V^{4+}$  (3.92 V) and  $V^{4+}/V^{4+}$ V<sup>3+</sup> (3.20 V),<sup>41,42</sup> which are retained when the rates are increased from 0.5C to 10C and then reset to 3C. The largest polarization between discharge and charge is only 0.34 V versus the charge plateau of 3.54 V, indicating a high energy storage efficiency of above 90%. Finally, we test long-term charge/discharge cycling performance at a rate of 10C. As shown in Fig. 6g, the initial capacity is 107.9 mA h  $g^{-1}$  of which 81% is retained after 560 cycles. A detailed comparison with other reported solid-state sodium batteries<sup>15,18,25,28,35</sup> is provided in Table S3<sup>†</sup> to further emphasize the virtue of our GBS design, which provides promising application in solid-state metal batteries.

#### Conclusions

In summary, we demonstrate a grain boundary sealed Na<sub>3</sub>Zr<sub>2</sub>-Si<sub>2</sub>PO<sub>12</sub> (GBS-NZSP) solid electrolyte synthesized by a liquidphase sintering method using the (ZnO)2-(B2O3)3 additive to address the issues of high interfacial resistance and metal dendrite penetration. The GBS-NZSP possessing a dense microstructure and ZBO-strengthening grain boundary exhibits a desired interfacial resistance of as low as 23.3  $\Omega$  cm<sup>2</sup> against Na metal and ultra-stable Na plating/stripping cycles at 0.3 mA cm<sup>-2</sup> for 1400 h at room temperature. The satisfactory interfacial performance facilitates a solid-state sodium metal battery of Na<sub>3</sub>V<sub>1.5</sub>Cr<sub>0.5</sub>(PO<sub>4</sub>)<sub>3</sub>/GBS-NZSP/Na, which is featured with a low resistance of 175  $\Omega$  cm<sup>2</sup> and exhibits superior electrochemical performance at room temperature. An initial coulombic efficiency of 94.2% and subsequent excellent high-rate capability are manifested from 0.5C to 10C. A high capacity of 108.1 mA h  $g^{-1}$  is delivered with 81% retention after 560 charge/discharge cycles at 10C rate. Our results present a well-designed Na+-ion solid electrolyte advantageous in application of solid metal batteries and promote the research advance of new-type solid-state batteries (i.e. solid-state Na-S, Na-O<sub>2</sub>, Na-CO<sub>2</sub> batteries, etc.).

# Conflicts of interest

There are no conflicts to declare.

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